

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L39	208097	gate and source and drain	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/17 18:13
L40	2065329	substrate wafer	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/17 18:14
L49	620850	(groove trench\$2 recess\$2 opening) with (ring around\$3 surround\$3)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/17 18:49
L50	84959	(groove trench\$2 recess\$2 opening) with (gate polysilicon)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/17 18:49
L51	4582	39 and 40 and 49 and 50	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/17 18:49
L53	4064	51 and (@ad<"20020628" @rlad<"20020628")	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/17 18:52
L54	2207	H01L029/872 H01L029/76	JPO	OR	ON	2004/11/17 18:52